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(54) Coated cemented carbide endmill having hard-materials-coated-layers excellent in adhesion

A coated cemented carbide endmill, comprising a tungsten carbide based cemented carbide substrate having a composition of 5 - 20 wt% of Co as a binder phase forming component, when necessary, 0.1 - 2 wt% of one or two of Cr and V as the binder phase forming component, 0.1 - 5 wt% of one kind or more kinds of carbides and nitrides of Ti. Ta. Nb and Zr as well as two or more kinds of solid solutions thereof as a dispersed phase forming component and the balance being tungsten carbide as the dispersed phase forming component and inevitable impurities, wherein the tungsten carbide has a refined particle structure having an average particle size of 0.1 - 1.5 µm, the tungsten carbide based cemented carbide substrate has a surface layer formed to the surface portion thereof which is formed by being heated at a high temperature and in which composite carbides created by the reaction of Co and W are distributed over a depth of 0.1 - 2 µm from the uppermost surface at the cutting edge thereof and further the cemented carbide substrate has hard-material-coated layers composed of a Ti compound layer and, when necessary, an aluminum oxide layer formed thereto in an average layer thickness of 0.5 - 4.5 µm, the Ti compound layer being composed of one or more layers of a Titanium carbide, Titanium nitride, Titanium carbo-nitride, Titanium oxy-carbide, Titanium oxy-nitride and Titanium oxy-carbo-nitride formed by medium temperature chemical vapor deposition and the aluminum oxide layer being formed by medium temperature chemical vapor deposition or high temperature chemical vapor deposition. With this arrangement, there can be provided a coated cemented carbide endmill having hard-material-coated layers excellent in an adhesion.

The MT-CVD for blaus is For C. Cumented curbides. No CCBN's.

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Description

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BACKGROUND OF THE INVENTION

1. Field of the Invention

[0001] The present invention relates to a coated cemented carbide endmill exhibiting excellent wear resistance for a long period of time because even if the endmill is used in high speed cutting, the hard-material-coated-layers of the endmill are not exfoliated due to the excellent adhesion thereof.

2. Description of the Related Art

[0002] Conventionally, there is known coated cemented carbide endmills composed of a tungsten carbide (hereinafter, shown by WC) based cemented carbide substrate (hereinafter, simply referred to as a cemented carbide substrate) having a surface portion to which formed, in an average layer thickness of 0.5 - 5 μm, are hard-material-coated-layers composed of a Ti compound layer which is composed of one or more layers of a Titanium carbide (TiC), Titanium nitride (TiN), Titanium carbide-nitride (TiCN), Titanium oxy-carbide (TiCO), Titanium oxy-nitride (TiNO) and Titanium oxy-carbo-nitride (TiCNO), each of the hard-material-coated-layers being formed by medium temperature chemical vapor deposition (a method generally referred to as MT-CVD by which vapor deposition is performed at 700 - 980°C which is relatively lower than the vapor deposition temperature 1000 - 1150°C employed by ordinary high temperature chemical vapor deposition (hereinafter, referred to as HT-CVD)), as shown in, for example, Japanese Unexamined Patent Publication No. 62-88509.

[0003] Recently, since labor and energy are greatly saved in a cutting process, there is a tendency that a cutting speed as one of cutting conditions is further more increased accordingly. When the conventional coated cemented carbide endmills are used under such high speed condition, the hard-material-coated layers are liable to be exfoliated due to their insufficient adhesion, by which the endmills are remarkably worn and their life is ended in a relatively short time.

[0004] To cope with this problem, the inventors directed attention to the conventional coated cemented carbide endmills from the above point of view and made studies to improve the adhesion of the hard-material-coated layers constituting the endmills. As a result, the inventors have obtained a conclusion that when a coated cemented carbide endmill is arranged as shown in the following items (a), (b) and (c), the adhesion of the Ti compound layer to the surface of the cemented carbide substrate of the endmill is greatly improved by a surface layer which is formed to the surface portion thereof by being heated at a high temperature and thus the hard-material-coated layer of the coated cemented carbide endmill is not exfoliated even if the endmill is used in high speed cutting and the endmill exhibits excellent wear resistance for a long time:

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(a) the cemented carbide substrate has a composition of 5 - 20 wt% of Co (hereinafter, % shows wt%) as a binder phase forming component, further when necessary, 0.1 - 2% of one kind or two kinds of Cr and V as the binder phase forming component, further when necessary, 0.1 - 5% of one kind or more kinds of carbides, nitrides and carbonitrides of Ti, Ta, Nb and Zr (hereinafter, shown as TiC, TiN, TiCN, TaC, TaN, TaCN, NbC, NbN, NbCN, ZrC, ZrN and ZrCN, respectively) as well as two or more kinds of solid solutions thereof (hereinafter, they are shown as (Ti, Ta, Nb, Zr) C · N as a whole) as a dispersed phase forming component and the balance being WC as the dispersed phase forming component and inevitable impurities, wherein the WC has a refined particle structure having an average particle size of 0.1 - 1.5 μm;

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(b) when the cemented carbide substrate shown in (a) is heated at a high temperature in a hydrogen atmosphere in which a carbon dioxide gas or titanium tetrachloride is blended under conditions that the atmosphere is set to a pressure of 50 - 550 torr and the substrate is held at a temperature of 900 - 1000° C for 1 - 15 minutes, a surface layer created by the reaction of composite carbides of Co and W (hereinafter, shown by Co_mW_nC) is formed to the surface portion of the base substance over a predetermined depth from the uppermost surface at the cutting edge thereof.

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(c) hard-material-coated layers composed of a Ti compound layer and, when necessary, an aluminum oxide (hereinafter, shown by Al₂O₃) layer are formed to the surface of the substrate having the surface layer which is formed by being heated at the high temperature and in which the reaction-created Co_mW_nC shown in (b) is distributed, wherein the Ti compound layer is composed of one or more layers of a Tic, TiN, TiCN, TiCO, TiNO and TiCNO using MT-CVD and the aluminum oxide layer is formed using MT-CVD or HT-CVD.

SUMMARY OF THE INVENTION

[0005] The present invention achieved based on the result of the above studies is characterized in a coated cemented

carbide endmill having hard-material-coated layers excellent in an adhesion, the endmill comprising a tungsten carbide based cemented carbide substrate having a composition of 5 - 20 wt% of Co as a binder phase forming component, further when necessary, 0.1 - 2% of one kind or two kinds of Cr and V as the binder phase forming component, further when necessary, 0.1 - 5% of one kind or more kinds of (Ti, Ta, Nb, Zr) C · N as a dispersed phase forming component and the balance being WC as the dispersed phase forming component and inevitable impurities, wherein the WC has a refined particle structure having an average particle size of $0.1 - 1.5 \,\mu\text{m}$, the cemented carbide substrate has a surface layer formed to the surface portion thereof which is formed by being heated at a high temperature and in which reaction-created $\text{Co}_m\text{W}_n\text{C}$ is distributed over a depth of $0.1 - 2 \,\mu\text{m}$ from the uppermost surface at the cutting edge thereof and further the substrate has coated layers composed of a Ti compound layer and, further when necessary, an Al_2O_3 layer formed thereto in an average layer thickness of $0.5 - 4.5 \,\mu\text{m}$, the Ti compound layer being composed of one or more layers of a TiC, TiN, TiCN, TiCO, TiNO and TiCNO using MT-CVD and the Al_2O_3 layer being formed using MT-CVD or HT-CVD.

[0006] Next, reasons why the compositions of the cemented carbide substrate constituting the coated cemented carbide endmill of the present invention, the average particle size of WC particles and the distributed depth of Co_mW_nC and the average layer thickness of the hard-material-coated layers are limited as described above will be described.

(a) Co content

[0007] Co has an action for improving a sinterability and thereby improving the toughness of the cemented carbide substrate. When a Co content is less than 5%, however, a desired toughness improving effect cannot be obtained, whereas when the Co content is larger than 20%, not only the wear resistance of the cemented carbide substrate itself is lowered but also the cemented carbide substrate is deformed by the heat generated in high speed cutting. Thus, the Co content is set to 5 - 20% and preferably to 8 - 12%.

5 (b) Cr and V

[0008] Cr and V are contained in a necessary amount because they are dissolved in solid in Co as the binder phase forming component to thereby strengthen it as well as contribute to refine the WC particles and further have an action for promoting the formation of the reaction-created Co_mW_nC which is distributed in the surface layer formed by being heated at the high temperature to thereby improve the adhesion of the hard-material-coated layers achieved by the reaction-created Co_mW_nC . When their content is less than 0.1%, however, it cannot be expected that the above action achieves a desired effect, whereas when their content is larger than 2%, the above action is saturated and an improving effect cannot be further enhanced. Thus, their content is set to 0.1 - 2% and preferably to 4 - 0.8%.

[0009] When the coated cemented carbide endmill is made, it is preferable that Cr and V as the binder phase forming component are used in the form of carbides, nitrides and oxides of Cr and V (hereinafter, shown as Cr₃C₂, CrN, Cr₂O₃, VC, VN and V₂O₅ and further shown as (Cr, V) C • N • O as a whole) as material powders. Since these material powders are dissolved in solid in Co as the binder phase forming component when sintering is carried out and form a binder phase, a precipitate containing Cr and V as one of components cannot be observed by an optical microscope or a scanning electron microscope.

(c) (Ti, Ta, Nb, Sr) C · N

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[0010] Since these components have an action for improving the wear resistance of the cemented carbide substrate, they are contained in a necessary amount. When their content is less than 0.1%, however, a desired wear resistance improving effect cannot be obtained, whereas when it is larger than 5%, toughness is lowered. Thus, their content is set to 0.1 - 5% and preferably 1 - 2.5%.

(d) Average particle size of WC

[0011] It is intended to improve the strength of the cemented carbide substrate by the refined particle structure of WC particles and the refined particle structure is obtained by setting the particle size of WC powder used as material powder to 1.5 μ m or less. Accordingly, when the average particle size of the material powder is larger than 1.5 μ m, a desired strength improving effect cannot be obtained, whereas when it is less than 0.1 μ m, wear resistance is lowered. Thus, the average particle size of the WC powder is set to 0.1 - 1.5 μ m and preferably to 0.6 - 1.0 μ m.

(e) Average distributed depth of ComWnC

[0012] Since the portion of the endmill which contributes to cutting is a cutting edge and the portion of the endmill

which is far from the cutting edge does not contribute to the cutting, the average distributed depth of Co_mW_nC is important at the portion of the cutting edge. Thus, the average distributed depth will be prescribed here. When the average distributed depth of Co_mW_nC is less than 0.1 μ m, the ratio of it distributed in the surface layer formed by being heated at the high temperature is too small for the Co_mW_nC to secure a desired excellent adhesion to the hard-material-coated layers, whereas when the average distributed depth thereof is larger than 2 μ m, since ratio of the average distributed depth of the Co_mW_nC in the uppermost surface portion of the cemented carbide substrate is made excessively large, chipping is liable to be caused to a cutting edge. Thus, the average distributed depth is set to 0.1 - 2 μ m and preferably to 0.5 - 1.5 μ m.

(f) Average layer thickness of the hard-material-coated layers

[0013] When the average layer thickness of the hard-material-coated layers is less than 0.5 μ m, desired excellent wear resistance cannot be obtained, whereas when the average layer thickness is larger than 4.5 μ m, chipping is liable to be caused to the cutting edge. Thus, the average layer thickness is set to 0.5 - 4.5 μ m and preferably to 1.5 - 2.5 μ m.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0014] A coated cemented carbide endmill of the present invention will be specifically described with reference to embodiments.

(Embodiment 1)

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[0015] WC powder having a predetermined average particle size within the range of 0.1 - 1.5 µm, various carbide powder, nitride powder and carbo-nitride powder each having the average particle size of 0.5 µm as shown in Table 1 and Table 2 and constituting (Ti, Ta, Nb, Zr) C • N and Co powder having the average particle size of 0.5 µm were prepared as material powders. These material powders were blended to the composition shown in Table 1 and Table 2 likewise, wet mixed in a ball mill for 72 hours and dried and thereafter pressed to green compact at the pressure of 1 ton/cm² and the green compact was vacuum sintered under conditions that it was held for one hour in the vacuum of 1 × 10⁻³ torr at a predetermined temperature within the range of 1350 - 1500°C and cemented carbide substrates a - z which had compositions substantially similar to the above blended compositions and comprised WC particles having the average particle sizes shown in Table 1 and Table 2 were formed.

[0016] Further, cemented carbide substrates A - Z were made by forming a surface layer formed by being heated at a high temperature to the surface portion of each of the cemented carbide substrates a - z under the conditions shown in Table 3 and Table 4, the surface having Co_mW_nC distributed therein over the average depths shown in Table 3 and Table 4.

[0017] Subsequently, hard-material-coated layers having the compositions and the average layer thicknesses shown in Table 6 and Table 7 were formed under the conditions shown in Table 5 to the surface of each of the cemented carbide substrates A - Z and coated cemented carbide ball-nose endmills of the present invention (hereinafter, referred to as coated endmills of the present invention) 1 - 26 were made. The endmills were composed of a shank portion and a two-flute portion and had a ball-nose radius of 5 mm and a nelix angle of 30°.

[0018] For the purpose of comparison, comparative coated cemented carbide endmills (hereinafter, referred to as comparative coated endmill) 1 - 26 were made, respectively under conditions similar to the above conditions except that cemented carbide substrates a - z, to which the surface layer formed by being heated at the high temperature was not formed, were used in place of the cemented carbide substrates A - Z having the above surface layer as shown in Table.

[0019] Next, high speed copy milling was carried out, by means of the resultant coated endmills 1 - 26 of the present invention and the resultant comparative coated endmills 1 - 26, to alloy steel in a dry state by alternately effecting downcut and up-cut milling under the following conditions and the worn width of the maximum flank face of the cutting edge of each of the endmills was measured.

material to be cut SKD61 (hardness: HRC 53) cutting speed: 800 m/min

feed per tooth: 0.1 mm/cutting edge

depth of cut: 0.5 mm width of cut: 0.5 mm length of cut: 250 m

Since the comparative coated endmills 1 - 26 were worn at a high speed, the cutting operation of them was interrupted

when the width of the maximum flank wear of the cutting edge reached 0.3 mm and the cut length up to that time was measured. Table 6 - Table 8 show the result of measurement, respectively.

(Embodiment 2)

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[0020] WC powder having a predetermined average particle size within the range of 0.1 - 1.5 μ m, Cr₃C₂ powder having the average particle size of 0.5 μ m and Co powder having the average particle size of 0.5 μ m were prepared as material powders. These material powders were blended at a predetermined blend ratio, wet mixed in a ball mill for 72 hours and dried and thereafter pressed to green compact at the pressure of 1 ton/cm² and the green compact was vacuum sintered under conditions that it was held for one hour in the vacuum of 1 × 10⁻³ torr at a predetermined temperature within the range of 1350 - 1500°C and cemented carbide substrates a - t which had the compositions shown in Table 9 and comprised WC having the average particle sizes shown in Table 9 were formed.

[0021] Further, cemented carbide substrates A - T were made by forming a surface layer formed by being heated at a high temperature to the surface portion of each of the cemented carbide substrates a - z under the conditions shown in Table 10, the surface layer having Co_mW_nC distributed therein over the average depths shown in Table 10.

[0022] Subsequently, hard-material-coated layers having the compositions and the average layer thicknesses shown in Table 12 were formed under the conditions shown in Table 11 to the surface of each of the cemented carbide substrates A - T and coated cemented carbide ball-nose endmills of the present invention (hereinafter, referred to as coated endmills of the present invention) 1 - 20 were made, respectively. The endmills were composed of a shank portion and a two-flute portion and had a ball-nose radius of 5 mm and a helix angle of 30°.

[0023] For the purpose of comparison, comparative coated cemented carbide endmills (hereinafter, referred to as comparative coated endmills) 1 - 20 were made, respectively under conditions similar to the above conditions except that cemented carbide substrates a - t, to which the surface layer formed by being heated at the high temperature was not formed, were used in place of the cemented carbide substrates A - T having the above surface layer as shown in Table. 13.

[0024] Next, high speed copy milling was carried out, by means of the resultant coated endmills 1 - 20 of the present invention and the resultant comparative coated endmills 1 - 20, to alloy steel in a dry state by alternately effecting downcut and up-cut milling under the following conditions and the worn width of the maximum flank face of the cutting edge of each of the endmills was measured.

material to be cut: SKD61 (hardness: HRC 53)

cutting speed: 500 m/min

feed per tooth: 0.1 mm/cutting edge

depth of cut: 0.5 mm width of cut: 0.5 mm length of cut: 350 m

Table 12 and Table 13 show the result of measurement, respectively.

(Embodiment 3)

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[0025] WC powder having a predetermined average particle size within the range of 0.1 - 1.5 μ m, various carbide powder, nitride powder, oxide powder and carbo-nitride powder each having the average particle size of 0.5 μ m and constituting (Ti,Ta, Nb, Zr) C · N and (Cr, V) C · N · O. Co powder having the average particle size of 0.5 μ m and carbon powder for adjusting an amount of carbon were prepared as material powders. These material powders were blended to a predetermined composition, wet mixed in a ball mill for 72 hours and dried and thereafter pressed to green compact at the pressure of 1 tor/cm² and the green compact was vacuum sintered under conditions that it was held for one hour in the vacuum of 1 × 10⁻³ torr at a predetermined temperature in the range of 1350 - 1500°C and cemented carbide substrates a - s which had the compositions shown in Table. 14 and comprised WC particles having the average particle sizes shown in Table 14 were formed.

[0026] Further, cemented carbide substrates A - S were made by forming a surface layer formed by being heated at a high temperature to the surface portion of each of the cemented carbide substrates a - s under the conditions shown in Table 15, the surface layer having Co_mW_nC distributed therein over the average depths shown in Table 15.

[0027] Subsequently, hard-material-coated layers having the compositions and the average layer thicknesses shown in Table 17 were formed under the conditions shown in Table 16 to the surface of each of the cemented carbide substrates A - S and coated carbide ball-nose endmills of the present invention (hereinafter, referred to as coated endmills of the present invention) 1 - 19 were made. The endmills were composed of a shank portion and a two-flute portion and

had a ball-nose radius of 5 mm and a helix angle of 30°.

[0028] For the purpose of comparison, comparative coated cemented carbide endmills (hereinafter, referred to comparative coated endmills) 1 - 19 were made, respectively under conditions similar to the above conditions except that cemented carbide substrates a - s, to which the surface layer formed by being heated at the high temperature was not formed, were used in place of the cemented carbide substrates A - S having the above surface layer as shown in Table. 18.

[0029] Next, high speed copy milling was carried out, by means of the resultant coated endmills 1 - 19 of the present invention and the resultant comparative coated endmills 1 - 19, to alloy steel in a dry state by alternately effecting downcut and up-cut milling, under the following conditions and the width of the maximum flank wear of the cutting edge of each of the endmills was measured.

material to be cut: SKD61 (hardness: HRC 53)

cutting speed: 650 m/min

feed per tooth: 0.1 mm/cutting edge

depth of cut: 0.5 mm width of cut: 0.5 mm time of cut: 50 min

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Table 17 and Table 18 show the result of measurement, respectively.

[0030] It is apparent from the results shown in Tables 6 - 8, 12, 13, 17 and 18 that the hard-material-coated layers of the coated endmills of the present invention were not exfoliated and the endmills thereby exhibited excellent wear resistance, whereas the hard-material-coated layers of the comparative coated endmills were exfoliated in the midway of cutting and the endmills were greatly worn by the exfoliation and their life was ended in a relatively short time.

[0031] In the coated carbide endmills of the present invention, since the adhesion of the hard-material-coated layers to the surface of the cemented carbide substrate is greatly improved by the ComWnC distributed in the surface layer formed to the surface portion of the base substance by being heated at the high temperature as described above, the hard-material-coated layers are not exfoliated not only when the endmills are used under usual cutting conditions but also even if they are used in high speed cutting. Accordingly, the coated cemented carbide endmills of the present invention exhibit excellent wear resistance for a long period of time.

Table 1

	Туре		Composition (wt%)	Average grain size of WC (µm)
35	Cemented carbide substrate	а	Co: 5, WC + impurities: balance	1.2
		b	Co: 8, WC + impurities: balance	0.8
		С	Co: 10, WC + impurities: balance	1.0
40		d	Co: 12, WC + impurities: balance	1.2
		е	Co: 15, WC + impurities: balance	0.6
		f	Co: 20, WC + impurities: balance	0.4
45		g	Co: 13, TiN: 2.5, WC + impurities: balance	0.4
45		h	Co: 10, TaC: 2, WC + impurities: balance	0.8
		i	Co: 6, NbC: 0.5, WC + impurities: balance	1.2
		j	Co: 5, ZrCN: 0.1, WC + impurities: balance	1.5
50		k	Co: 7, (Ti, Ta) N: 0.8, WC + impurities: balance	1.0
		ī	Co: 15, (Ti, Nb) CN: 3.5, NbCN: 0.5, WC + impurities: balance	0.5
		m	Co: 8, (Ti, Zr) CN: 1, WC + impurities: balance	0.6
55		n	Co: 8, (Ta, Nb) C: 1.5, WC + impurities: balance	1.0

Table 2

5	Type		Composition (wt%)	Average grain size of WC (μm)
	Cemented carbide	0	Co: 12, (Ta, Zr) C: 2, WC + impurities: balance	0.6
	substrate	р	Co: 6, (Zr, Nb) N: 1.2, NbN: 0.3, WC + impurities: balance	1.2
10		q	Co: 10, (Ti, Ta, Nb) C: 2.2, WC + impurities: balance	0.8
10		٢	Co: 20, (Ti, Ta, Zr) N: 5, WC + impurities: balance	0.1
		s	Co: 12, (Ti, Zr, Nb) CN: 2.5, WC + impurities: balance	0.6
	Ì	t	Co: 8, (Ta, Nb, Zr) C: 1, TiCN: 0.5, WC + impurities: balance	1.2
15		u	Co: 6, (Ti, Ta, Zr, Nb) C: 1, WC + impurities: balance	0.8
		v	Co: 10, TaN: 1.5, TiC: 0.5, WC + impurities: balance	1.2
		w	CO: 7, (Ti, Zr) C: 0.4, ZrN: 0.1, WC + impurities: balance	0.8
20		×	Co: 17, (Ti, Zr) N: 1, (Ti, Ta, Zr) C: 3, TaCN: 0.6, WC + impurities: balance	1.5
		у	Co: 12, TiC: 0.2, ZrC: 0.8, (Ta, Nb) C: 1, WC + impurities: balance	1.0
		Z	Co: 15, TiN: 0.5, TaC: 1, ZrCN: 1, NbC: 0.5, WC + impurities: balance	0.4

Table 3

5	Туре		Symbol of Surface layer formed by being heated at high temp substrate								
		Forming conditions									
10				Atmosp	here	Temperature (°C)	Holding time (min.)				
15				Ratio of composition blended to H ₂ (vol%)	Pressure (torr)						
	Cemented	Α	a	CO ₂ : 11	250	950	6	1.64			
	carbide sub- strate	181		TiCl ₄ : 2	550	900	11	0.83			
20	0	С	С	CO ₂ : 10	300	950	10	1.27			
	!	D		TiCl ₄ : 3	400	920	7	0.80			
		E	е	CO ₂ : 10	50	900	5	0.24			
		F	f	TiCl ₄ : 2	150	900	5	0.41			
25		G	g	TiCl ₄ : 2	450	900	10	1.73			
		Н	h	CO ₂ : 11	350	950	12	1.48			
		ı	i	CO ₂ : 9	550	1000	15	2.00			
30		J	j	TiCl ₄ : 1	300	950	10	0.99			
		К	k	TiCl ₄ : 3	50	1000	5	0.45			
		L	1	CO ₂ : 11	200	. 950	5	1.28			
35		М	m	CO ₂ : 9	80	900	6	0.31			

Table 4

	Type		Symbol of substrate	perature Average distrib-								
			· · · · · · · · · · · · · · · · · · ·		Forming conditions							
				Atmosph	nere	Temperature (°C)	Holding time (min.)					
				Ratio of com- posiblended to H ₂ (vol%)	Pressure (torr)			,				
15	Cemented	N	n	TiCl ₄ : 1	250	900	13	1.02				
	carbide sub-	0	0	TiCl ₄ : 3	450	950	11	0.56				
	strate	Р	р	Co ₂ : 9	300	1000	13	1.52				
20	ı	Q	q	CO ₂ : 10	500	950	15	1.80				
		R	r	TiCl ₄ : 1	100	900	6	0.53				
		s	s	TiCl ₄ : 3	450	1000	14	1.45				
		T	t	CO ₂ : 11	500	1000	15	1.82				
25		U	u	TiCl ₄ : 1	50	900	5	0.11				
		V	v	TiCl ₄ : 3	100	900	7	0.36				
		W	w	CO ₂ : 9	300	950	9	1.01				
30		X	x	TiCl ₄ : 2	450	900	10	1.98				
		Y	у	CO ₂ : 11	100	900	6	0.33				
		Z	z	TiCl ₄ : 2	400	950	8	1.01				

Table 5

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Type of hard-material- coated-layer	Hard-material-coated-layer forming conditions									
	Composition of reaction gas (vol%)	Reaction	atmosphere							
		Pressure (torr)	Temperature (°C)							
Al ₂ O ₃ *	Al ₂₁ Cl ₃ :4, CO ₂ : 10, H ₂ S: 0.2. HCl: 2, H ₁ : balance	50	1020							
Al ₂ O ₃	Al[OCH(CH ₃) ₂] ₃ : 0.3, H ₂ : balance	50	900							
TiC	TiCl ₄ : 2, C ₃ H ₈ : 5, H ₂ : balance	100	900							
TiN	TiCl ₄ : 2, N : 30, H : balance	100	850							
TiCN	TiCl ₄ : 2, N ₂ : 10, CH ₃ CN: 0.8, H ₂ : balance	70	900							
TiCO	TiCl ₄ : 3, CO: 2, H ₂ : balance	100	900							
TiNO	TiCl ₄ : 3, CO: 1, N ₂ : 15, H ₂ : balance	50	900							
TICNO	TiCl ₄ : 3. CO: 2, N ₂ : 15, H ₂ : balance	50	900							

[In Table 5, item with 'shows high temperature chemical vapor deposition (HT-CVD) and items medium temperature chemical vapor deposition (MT-CVD).]

Table 6

_				0					(n						
Width of	max-flank	wear of cutting edge	0 13	60.0	90.0	01.0	91		0.10	0.13	0.03	0.18	0.13	0.18	
shown in		Fifth layer	T1N(0.3)		TiN(0,2)	:	;								
er thickness is	und I	Pourth layer	T1CO(0.1)		A1,0,(0.5)*							A1.0.(1.0)	1		TIN(0.2)
er (average lay	parentheses, unitypm	Third layer	A1,0,(0.5)*	A1,0,(0.2)	TICNO(0.1)	T1N(0.1)			A1.0,(0.1)		T1CN(0.9)	T1CNO(0.1)		A1,0,(0.5)*	
Hard-material-coated-layer (average layer thickness is shown in	par	Second layer	T1CNO(0.1)	T1CO(0.3)	T1CN(1.8)	T1CNO(0.5)	T1CN(0.2)		T1CNO(0.1)	A1,0,(0.4)*	T1C(0.5)	T1CN(0.9)	T1CH(4.4)	T1C(2.5)	T1NO(0.1)
Hard-mate		First layer	T1CH(0.9)	T1C(0:S)	T1N(0.1)	T1C(1.9)	T1N(0.8)	T1CN(2.0)	T1CH(0.3)	T1CH(1.6)	T1N(0.1)	T1C(1.0)	T1C(0.1)	T1N(0.5)	T1CH(1.3)
Symbol of	2000		A	æ	ວ	Q	ĸ	4	ט	=	I ,	י	ĸ	1	x
			1	2	3	4	2	9	7	80	6	10	11	12	13
Туре			Coated	endm111	of the present	invention									

[In Table 6, item with * shows hard-material-coated-layer made by high temperature chemical vapor deposition and items without * show hard-material-coated-layers made by medium temperature chemical vapor deposition, respectively.]

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						(<u>a</u>	((m)			_	-	(j	g)	
Width of max- flank wear of	500 600000	0.07	60.0	0.17	0.17	0.13	0.09	0.19	0.14	0.18	0.09	0.20		0.10	0.12	
hown in	Fifth layer		**	T1H(0.3)	-	A1,0,(0.2)*	:	:	:	;	:			:	:	
Hard-material-coated-layer (average layer thickness is shown in parentheses, unit;µm	Fourth layer	A1,0,(0.2)*		T1NO(0:1)		T1CNO(0.5)	A120,(0.2)	T1N(0.5)	A1:0,(0.1)				-		-	
layer (average layer parentheses, unit:pm	Third layer	T1CNO(0.1)	A1,0,(0.1)	T1CN(2.0)	TIN(0.1)	T1C(1.0)	T1CNO(0.1)	T1CN(1.5)	T+CNO(0.1)		210 010	021010121	:	A1,0,(0.1)*	L 1	
erial-costed-lay	Second layer	T(CN(1.2)	T1CNO(0.1)	T1C(2.0)	T1CH(1.4)	T1CN(1.0)	T1CN(3.0)	P(C(1.0)	BIONII OI	Tich(Tro)	(CO)NII	T1CN(4.1)		T1CNO(1.4)	110 (0.5)	A110101
Hard-mat	Pirst layer	T CINTE	T10(0.5)	T1N(0.1)	T1N(0.1)	T1N(0.1)	#1N(0.2)	min(0 g)	(200)	TIN(U.1)	T1CK(4.0)	T1N(0.1)	T1H(0.5)	T1CN(0.3)	10 678070	TICN(3.0)
Symbol of substrate		,	E C	٩		2 2	: 0	, 6	÷	9	۸	*	×	*	-	1 0
		1	¥ :	£ ;	3 :	1	:	2 2	2	77	22	23	24	3,		76
Туре			Coated	endmill of the	present	a									-	

[In Table 7, items with * show hard-material-coated-layers made by high temperature chemical vapor deposition and items without * show hard-material-coated-layers made by medium temperature chemical vapor deposition, respectively.]

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Result of cutting test	life ended in 175 m	life ended in 150 m	life ended in 100 m	life ended in 125 m	life ended in 150 m	11fe ended in 150 m	life ended in 125 m	11fe ended in 130 m	11fe ended in 100 m	11fe ended in 175 m	life ended in 150 m	life ended in 200 m	11fe ended in 150 m
Hard-material-coated-	similar to coated. carbide endmill 14 of the present invention	similar to coated carbide endmill 15 of the present invention	similar to coated carbide endmill 16 of the present invention	gimilar to coated carbide endmill 17 of the present invention	similar to coated carbide endmill 18 of the present invention	eimilar to coated carbide endmill 19 of the present invention	similar to coated carbide endmill 20 of the present invention	similar to coated carbide endmill 21 of the present invention	similar to coated carbide endmill 22 of the present invention	similar to coated carbide endmill 23 of the present invention	similar to coated carbide endmill 24 of the present invention	similar to conted carbide endmill 25 of the present invention	similar to coated carbide endmill 26 of the present invention
Symbol of	u	0	O.	ט	ı	to .	د	B	>	*	*	Å	и .
	=	2	92	11	22	13	20	21	22	23	77	35	28
Type	Comparative coated carbide	endmilli									.	,	· · · · ·
Result of	life ended in 175 m	life ended in 150 m	life ended in 200 m	life ended in 125 m	life ended in 125 m	life ended in 150 m	life ended in 150 m	life ended in 200 m	life ended in 125 m	life ended in 150 m	life ended in 100 m	life ended in 150 m	11fe ended in 200 m
Hard-material-coated-	similar to coated carbide endmill 1 of the	similar to coated carbide endmill 2 of the carbide endmill 2 of the	similar to coated carbide endmill 3 of the nresent invention	eimilar to costed carbide endmill 4 of the present invention	eimilar to coated carbide endmill 5 of the present invention	similar to coated carbide endmill 6 of the nresent invention	similar to coated carbide endmill 7 of the present invention	similar to coated carbide endmill 8 of the present invention	similar to coated carbide endmill 9 of the present invention	estable to conted contide of the present invention	similar to coated carbide endmill 11 of	similar to coated carbide endmill 12 of the present invention	aimilar to coated carbide endmill 13 of
Symbol of	substrate.	م	О	8	6		5	д	1	-	×	1	5
	-	n	m	1.	5	•	-		٥	2	#	12	13
e unit	Comparative	corbide endaill			1								

Table 9

Type Composition (wt%)	Average grain size of WC (µm)
5	
Co Cr V WC + impu	rities
Cemented carbide substrate a 8.1 0.52 0.10 balance	e 0.52 ·
b 9.8 0.40 0.21 balance	e 0.76
c 7.8 0.28 0.12 balance	e 0.95
d 10.3 0.11 0.30 balanc	
e 12.4 0.23 0.45 balance	e 0.51
f 11.6 0.78 0.22 balance	ce 0.80
g 19.7 1.71 0.31 balance	
h 15.1 0.13 0.08 balance	ce 1.23
i 10.2 - 1.52 balance	ce 0.30
j 7.9 - 0.61 balanc	ce 1.17
k 5.0 - 0.11 balanc	ce 1.50
I 9.6 - 0.48 balan	ce 0.82
m 6.3 - 0.29 balan	ce 0.12
n 19.8 - 0.13 balan	ice 1.54
o 10.1 0.82 - balan	nce 1.04
p 8.0 0.55 - balan	nce 0.51
g 6.1 0.32 - balan	nce 1.47
r 17.8 1.54 - balar	nce 0.33
s 15.2 0.96 - balar	nce 0.80
t 12.0 1.03 - balar	nce 0.49

Table 10

5	Туре		Symbol of substrate	Surfac	ce layer form	ned by being hea	ated at high tem	perature
					Forming	g conditions	,	Average distrib- uted depth of Co _m W _n C (µm)
10				Atmosp	here	Temperature (°C)	Holding time (тіп.)	
15				Ratio of com- position blended to H ₂ (vol%)	Pressure (torr)			
	Cemented	Α	а	CO ₂ : 11	250	1000	5	0.96
	carbide sub- strate	В	b	TiCl ₄ : 2	450	950	1	0.52
20		С	С	CO ₂ : 9	350	1000	10	1.52
		D	d	TiCl ₄ : 2	550	900	7	1.04
		Е	е	TiCl ₄ : 3	500	1000	7	1.50
05		F	f	TiCl ₄ : 1	300	900	7	0.48
25		G	g	TiCl ₄ : 2	50	900	1	0.12
		Ŧ	h	CO ₂ : 9	200	950	3	0.31
		1	i	TiCl ₄ : 1	400	950	7	1.06
30		j	j	TiCl ₄ : 2	450	. 950	7	1.33
		К	k	CO ₂ : 10	550	1000	10	1.95
		L	I	CO ₂ : 9	250	950	5	0.51
35		М	m	TiCl ₄ : 3	550	1000	7	1.80
		N	n	CO ₂ : 9	500	1000	16	1.76
		0	0	TiCl ₄ : 2	400	950	. 5	0.97
		Р	р	TiCl ₄ : 2	500	950	16	1.46
40		Q	q	TiCl ₄ : 3	200	900	3	0.30
		R	r	TiCl ₄ : 1	550	950	10	1.89
		S	s	CO ₂ : 10	100	900	1	0.28
45		Т	· t	CO ₂ : 11	200	950	3	0.47

Table 11

50	Type of hard-material- coated-layer	Hard-material-coated-layer fo	orming conditions	
		Composition of reaction gas (vol%)	Reaction	atmosphere
			Pressure (torr)	Temperature (°C)
55	Al,O ₃ *	Al ₂ Cl ₃ : 4, CO ₂ : 10, H ₂ S: 0.2, HCl: 2, H ₂ : balance	50	1020
	Al ₂ O ₃	Al[OCH(CH ₃) ₂] ₃ : 0.3, H ₂ : balance	50	900

Table 11 (continued)

Type of hard-material- coated-layer	Hard-material-coated-layer	forming conditions	
	Composition of reaction gas (vol%)	Reaction	atmosphere
•		Pressure (torr)	Temperature (°C)
TiC	TiCl ₄ : 2, C ₃ H ₈ : 5, H ₂ : balance	100	900
TiN	TiCl ₄ : 2, N ₂ : 30, H ₂ : balance	100	850
TiCN	TiCl ₄ : 2, N ₂ : 10, CH ₃ CN: 0.8, H ₂ : balance	70	900
TiCO	TiCl ₄ : 3, CO: 2, H ₂ : balance	100	900
TiNO	TiCl ₄ : 3, CO: 1, N ₂ : 15, H ₂ : balance	50	900
TiCNO	TiCl ₄ : 3, CO: 2, N ₂ : 15, H ₂ : balance	50	900

medium temperature chemical vapor deposition (MT-CVD).]

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		(-	4)						1	EP	U	g g		00	י ט	ne	(v		(5	(<u>-</u>					
Worn width of	Wear of	outting edge	0.03	0.06	0.18	0.07		0.13	0.09	0.18	0.11	0.13	1	0.08	0.00	0.15	12		0.19	0.08	0.07	0.11	21.0		0.18	0.19	
s shown in		Fifth layer	:			;	-:-	TIN(0.3)	-		44N(0.1)		;	:	:		:	-	;	.:	:		:	:	;	:	
eer thiokness 5	layar (average tayer tittering parentheses, unit; parentheses,	Pourth layer	10 00	A120310:47				T1NO(0.1)		10 0/2/1	11 0,000	T1C0(0.1)		;	16 3,111	TIN(0.4)	:		!	11 0 (10.1)			A1,0,(1.0)		:		
	er (average la centhoses, unit	Third layer		T1CN0(0.1)	A1,0,(0.1)*	-:	;	T1CN(2.0)		٨٠٠٥١ (١٠٠٥)	TICH(1.5)	A1,0,(0.3)*	A1,0,(0.2)			A1,0,(0.4)*	T1CN(0.9)	A1,0,(0.1)	:	11, 0,000	TACHOLOGY	A1,0,(0.3)*	T1CN0(0.1)	TIN(0.1)	(0.1)Nte		-
	Herd-meteriel-coeted-layer (average perentheses, u	Record layer		T1CN(3.0)	T1CNO(1.4)	- 1	A1,0,(0.4)*	10 5357	TICLES	T1C(2.5)	T1C(1.0)	T1CNO(0.1)	T1CO(0.3)		Ticalu.	T1NO(0.1)	T1C(0.5)	#1CNO(0.1)			T1CN(1.2)	T1CN(2.1)	T1CN(0.9)	T1CR0(0.5)		TICH(1.4)	T1CH(4.4)
	Hard-mater		First tayer	T1N(0.2)	T1CN(0.3)	T1CN(2.0)	#4CN(1.6)		T1N(0.1)	T1N(1.0)	T18(0.5)	T1CH(0.9)	march R)	17010:31	T1N(0.8)	T1CN(1.3)	T1H(0.1)	16.070	TICIOISI	T1N(0.6)	TIN(0.1)	T1N(0.1)	T1C(1.0)	10 1101	TICLAS	T1N(0.1)	T1C(0.1)
	Symbol of	substrate		×	В	U	١	4	26	۵.	9	=		I	2	<u>_</u>	-		±	Z	0	۵	0		~	B	ř
8				-	,		,	-	,	۰	-		•	6	10	=		:	13	1.	13	19			18	19	50
Table 12	TYDO	•		Potent	osrbide	of the	1nvention			,	,		-														

[In Table 12, items with * show hard-material-coated-layars made by high temperaturs chemical vapor deposition and items without * show hard-material-coated-layers made by medium temperature chemical vapor deposition, respectively.]

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								waath of
Туре		Symbol of		Hard-m	Hard-material-coated-layer	i-layer		max-flank
		Rubacrace	First layer	Second layer	Third layer	Fourth layer	Fifth layer	cutting
				to coated carbide	endmill 1	of the present	invention	0.32
Comparative		es) .	Similar	to coated	endmill 2	the present	invention	0.34
carbide endmill	7	۵	TOTTINE STATE	3 5	endm111 3	of the present	invention	0.43
	m		TOTTUTE	to cource	endmill 4	the present	invention	0.31
	▼	8	2444194	to contact	endmill 5	of the present	invention	0.42
	2	0	TOT THE P	to coated		of the present	invention	0,35
	اه	1	20711110	to coated	de endmill 7	of the present	invention	0.41
		6	Station.	to coated	de endmill 8	of the present	invention	0.35
	<u> </u>	٤,	otmilar atmilar	to coated		of the present	invention	0.38
	<u>م</u> :	-	o fmt lar	to coated	de endm111 10	of the present	invention	0.31
	:	<u>.</u>	Tel faite	to coated	carbide endmill 11	of the present	invention	0.33
		۷,	Tal Ambo	to coated	carbide endmill 12	of the present	invention	0.40
		1	raf labo	to coated	de endm111 13	of the present	invention	0.37
	<u>: </u> :	2 .	Tal lar	to conted		of the	invention	0.46
	1	<u>-</u>	Tel late	to coated	de endmill 15	of the present	invention	0.32
	2 3	- ·	Telmia	: 2	de endmill 16	of the present	invention	0.32
	1 5	2 6	similar	to coated	ide endmill 17	of the present	. invention	0.37
	: =	p 5-	similar	to coated	carbide endmill 18	of the present	: invention	0.39
	=		similar	\$	ide endmill 19	of the present	t invention	0.43
		1	Tal tal	to coated	carbide endmill 20	of the present invention	t invention	0.44

Table 14

5	Туре				•	Composition (wt%)		Average grain size of WC (μm)
ŀ			Co	Cr	٧	(Ti, Ta, Nb, Zr) C · N	WC + impurities	
-	Cemented carbide	a	12.0	0.48	0.50	TiC: 1.9	balance	0.9
	substrate	ь	7.9	0.23	1.02	TaN: 0.5	balance	1.2
10		С	14.8	1.41	-	TaCN:1.5	balance	0.4
1		d	10.1	1.42	0.51	NbN: 1.3	balance	0.5
1		е	17.8	•	1.55	NbCN: 3.3	balance	0.2
15		1	5.3	-	0.10	ZrCN: 0.9	balance	1.3
		g	9.8	0.52	-	TaC: 1.0	balance	1.0
		h	12.1	-	0.16	NbC: 3.0	balance	0.5
		 	7.8	0.39	·	ZrN: 1.2	balance	1.5
20		 	14.7	-	1.21	TiCN: 4.1	balance	1.0
		k	5.0	0.20	1.	TiN: 0.5	balance	1.0
	Ì	1	15.2	1.23	1.	ZrC: 2.3	balance	0.3
25		m	11.9	1.04	1.	(Ta, Nb) C: 1.5	balance	0.5
		n	10.2	0.79	 -	TaC: 0.5, ZrN: 0.5	balance	0.8
		6	5.3	-	0.17	(Ti, Ta, Zr) C: 0.1	balance	1.5
		p	19.8	0.87	0.97	(Ti, Ta, Nb, Zr) C: 5.0	balance	0.1
30		q	8.1	-	0.39	(Ti, Zr) C: 1.0, NbC: 0.1	balance	1.2
		r	16.9	-	1.98	(Ta, Nb) C: 0.5, TaC: 1.0	balance	0.5
35		s	9.8	0.89	-	Tic: 0.2, TaN: 0.8 NbC: 0.2, ZrCN: 1.6	balance	0.5

Table 15

					Table 15			
5	Туре		Symbol of substrate	Surfac	ce layer formed	by being heated	d at high tempe	rature
10						conditions		Average dis- tributed depth of Co _m W _n C (µm)
				Atmos	phere	Temperature (°C)	Holding time (min.)	
15	·			Ratio of com- position blended to H ₂ (vol%)	Pressure (torr)			
	Cemented	Α	а	CO ₂ : 9	500	950	13	1.22
20	carbide sub- strate	В	b	TiCl ₄ : 3	350	950	8	0.54
		С	С	CO ₂ : 11	400	900	15	1.01
	i	D	d	TiCl ₄ : 2	250	950	6	0.87
25		Ε	е	CO ₂ : 10	150	950	2	0.30
		F	f	TiCl ₄ : 1	400	1000	8	1.13
		G	9	CO ₂ : 11	350	900	5	0.42
		Н	h	TiCl ₄ : 2	350	950	10	1.04
30		-1	i	CO ₂ : 10	400	1000	15	1.53
		J	j	TiCl ₄ : 3	450	900	13	1.31
		K	k	TiCl ₄ : 3	550	1000	15	1.94
35		٦	<u> </u>	CO ₂ : 9	500	950	10	0.87
		М	m	TiCl ₄ : 2	350	950	6	0.45
		N	n	CO ₂ : 10	400	920	8	0.51
40		0	0	CO ₂ : 11	200	900	4	0.34
		Р	р	CO ₂ : 9	50	900	2	0.11
		Q	q	TiCl ₄ : 1	300	1000	3	0.80
		R	r	TiCl ₄ : 1	150	950	7	0.23
45		S	S	TiCl ₄ : 2	100	900	5	0.17

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Table 16

	Type of hard-material- coated-layer	Hard-material-coated-layer fo	rming conditions	
F	<u> </u>	Composition of reaction gas (vol%)	Reaction	atmosphere
-		·	Pressure (torr)	Temperature (°C)
-	Al ₂ O ₃ *	Al ₂ Cl ₃ : 4, CO ₂ : 10, H ₂ S: 0.2, HCl: 2, H ₂ : balance	50	1020
⊢	Al ₂ O ₃	Al[OCH(CH ₃) ₂] ₃ : 0.3, H ₂ : balance	50	900
-	TIC	TiCl ₄ : 2, C ₃ H ₈ : 5, H ₂ : balance	100	900
\vdash	TiN	TiCl ₄ : 2, N ₂ : 30, H ₂ : balance	100	850
H	TiCN	TiCl ₄ : 2, N ₂ : 10, CH ₃ CN: 0.8, H ₂ : balance	70	900
ŀ	TiCO	TiCl ₄ : 3, CO: 2, H ₂ : balance	100	900
-	TiNO	TiCl ₄ : 3, CO: 1, N ₂ : 15, H ₂ : balance	50	900
-	TICNO	TiCl ₄ : 3, CO: 2, N ₂ : 15, H ₂ : balance	50	900

Table 17

Type		Symbol of substrate	Hard-mater	ial-coated-laye	or (average la	Hard-material-coated-layer (average layer thickness is shown in parentheses, unit; un	shown in	Width of max- flank wear of
			Piret layer	Second layer	Third layer	Fourth layer	Fifth layer	of a first to
coated	7	4	T1N(0.1)	T1CN(0.5)	T1C(0.5)	A1,0,(0.1)*	T1N(0.1)	0.08
carbids endmill	2	e e	TICN(2.1)	A1,0,(0.3)*	TIN(0.2)	-		0.08
of the present	3	υ	T1C(3.5)	T100(0.1)	A120,(0.3)		:	0.09
Invention	-	a	T1H(0.2)	T1CN(2.0)	£1C(0.3)	A1,0,(0.2)	1	0.07
	8	200	TIN(2.0)	-	:	:		0.18
_	۰	a.	T1CN(0.9)	A1,0,(0.1)	1			0.07
	,	G	TIN(0.1)	T1CN(3.0)	T1C(0.9)	T1CNO(0.1)	A1,0,(0.4)*	0.07
	8	×	T1C(3.0)	:		:	-	0.17
	9	-	TIN(0.1)	T1CN(1.8)	TIN(0.1)	:	•	0.16
	10	7	T1C(2.0)	T1N(1.0)	:	••	-	0.15
-	٦	×	T1CN(0.5)		:			0.19
	12	13	T1C(2.0)	A1,0,(0.5)	•	1		0.12
	51	Ξ	T1N(0.2)	T1CN(2.0)	T1NO(0.1)	A1,0,(0.5)*	T1N(0.2)	0.07
	=	×	TIN(0.1)	T1CN(1.0)	T1CNO(0.1)	A1,0,(0.5)*		0.06
	15	°	T1CN(1.5)	A1,0,(0.5)	-		;	0.08
	97	۵	T1CN(2.9)	F1CNO(0.2)	A1,0,(0.4)		;	0.12
	11	a	F1C(1.7)	T1CO(0.1)	A1,0,(0.2)			0.00
	2	E	T1CH(1.5)	TIN(0.1)	T1CH(1.5)	T1C(0.5)	A1,0,(0.4)*	0.07
	19	s	TIN(0.1)	T1CN(0.5)	T1C(0.2)	A1,0,(0.2)	:	0.08

[In Table 17, item with * shows hard-material-coated-layer made by high temperature chemical vapor deposition and items without * show hard-material-coated-layers made by medium temperature chemical vapor deposition, respectively.]

Table 18

	Туре		Symbol of substrate	Hard-material-coated-layer	Result of cutting test
5	Comparative coated carbide	1	а	similar to coated carbide endmill 1 of the present invention	life ended in 40 min
	endmill	2	b	similar to coated carbide endmill 2 of the present invention	life ended in 40 min
10		3	С	similar to coated carbide endmill 3 of the present invention	life ended in 35 min
		4	d	similar to coated carbide endmill 4 of the present invention	life ended in 45 min
15		5	e	similar to coated carbide endmill 5 of the present invention	life ended in 20 min
		6	f	similar to coated carbide endmill 6 of the present invention	life ended in 45 min
20		7	g	similar to coated carbide endmill 7 of the present invention	life ended in 45 min
		8	h	similar to coated carbide endmill 8 of the present invention	life ended in 20 min
25		9	i	similar to coated carbide endmill 9 of the present invention	life ended in 20 min
	,	10	j	similar to coated carbide endmill 10 of the present invention	life ended in 25 min
30		11	k	similar to coated carbide endmill 11 of the present invention	life ended in 20 min
	i	12	1	similar to coated carbide endmill 12 of the present invention	life ended in 30 min
35		13	m	similar to coated carbide endmill 13 of the present invention	life ended in 45 min
		14	n	similar to coated carbide endmill 14 of the present invention	life ended in 45 min
40		15	0	similar to coated carbide endmill 15 of the present invention	life ended in 40 min
		16	Р	similar to coated carbide endmill 16 of the present invention	life ended in 30 min
45		17	q	similar to coated carbide endmill 17 of the present invention	life ended in 35 min
		18	r	similar to coated carbide endmill 18 of the present invention	life ended in 45 min
50		19	s	similar to coated carbide endmill 19 of the present invention	life ended in 40 min (life is ended by exfoliation of hard-material- coated-layer in any case)

Claims

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A coated cemented carbide endmill having hard-material-coated layers excellent in an adhesion, comprising a
tungsten carbide based cemented carbide substrate, wherein the tungsten carbide has a refined particle structure
having average particle size of 0.1 - 1.5 μm, the tungsten carbide substrate has a surface layer in which carbide

(ComWnC) are distributed over a depth of 0:1 - 2 µm from the uppermost surface at the cutting edge thereof and further the cemented carbide substrate has the hard-material-coated layers composed of Ti compound layer formed thereto in an average layer thickness of 0.5 - 4.5 μm the Ti compound layer being composed of one or more layers of TiC, TiN, TiCN, TiCO, TiNO, TiCNO.

- 2. A coated cemented carbide endmill having hard-material-coated layers excellent in an adhesion, comprising a tungsten carbide based cemented carbide substrate, wherein the tungsten carbide has a refined particle structure having average particle size of 0.1 - 1.5 µm, the tungsten carbide substrate has a surface layer in which carbide (Co_mW_nC) are distributed over a depth of 0.1- 2 μm from the uppermost surface at the cutting edge thereof and further the cemented carbide substrate has the hard-material-coated layers composed of Ti compound layer and Al_2O_3 layer formed thereto in an average layer thickness of 0.5 - 4.5 μm , the Ti compound layer being composed of one or more layers of TiC, TiN, TiCN, TiCO, TiNO, TiCNO.
- A coated cemented carbide endmill having hard-material-coated layers excellent in an adhesion, comprising a tungsten carbide based cemented carbide substrate, wherein the tungsten carbide has a refined particle structure 15 having average particle size of 0.1 - 1.5 µm, the tungsten carbide substrate has a surface layer formed to the surface portion thereof which is formed by being heated at a high temperature and in which carbide (Co_mW_nC) created by the reaction of Co and W are distributed over a depth of 0.1-2 µm from the uppermost surface at the cutting edge thereof and further the cemented carbide substrate has the hard-material-coated layers composed of Ti compound layer formed thereto in an average layer thickness of 0.5 - 4.5 μm, the Ti compound layer being composed 20 of one or more layers of TiC, TiN, TiCN, TiCO, TiNO, TiCNO formed by medium temperature chemical vapor deposition at a temperature of 700 - 980 °C.
- 4. A coated cemented carbide endmill having hard-material-coated layers excellent in an adhesion, comprising a tungsten carbide based cemented carbide substrate, wherein the tungsten carbide has a refined particle structure having average particle size of 0.1 - 1.5 µm, the tungsten carbide substrate has a surface layer formed to the surface portion thereof which is formed by being heated at a high temperature and in which carbide (Co_mW_nC) created by the reaction of Co and W are distributed over a depth of 0.1- 2 µm from the uppermost surface at the cutting edge thereof and further the cemented carbide substrate has the hard-material-coated layers composed of Ti compound layer and Al₂0₃ layer formed thereto in an average layer thickness of 0.5 - 4.5 μm, the Ti compound layer 30 being composed of one or more layers of Tic, TIN, TiCN, TiCO, TiNO, TiCNO formed by medium temperature chemical vapor deposition at a temperature of 700 - 980 °C.
- 5. A coated cemented carbide endmill according to Claim 1 to 4, wherein said cemented carbide substrate have a composition of 5 - 20 wt% of Co as a binder phase forming component and the balance being tungsten carbide as 35 a dispersed phase forming component and inevitable impurities.
 - 6. A coated cemented carbide endmill according to Claim 1 to 4, wherein said cemented carbide substrate have a composition of 5 - 20 wt% of Co as a binder phase forming component, 0.1 - 2 wt% of Cr and/or V as a binder phase forming component and the balance being tungsten carbide as a dispersed phase forming component and inevitable impurities,
 - A coated cemented carbide endmill according to Claim 1 to 4, wherein said cemented carbide substrate have a composition of 5 - 20 wt% of Co as a binder phase forming component, 0.1 - 5 wt% of one or more kinds of carbides and nitrides of Ti, Ta, Nb and Zr as well as two or more kinds of solid solutions thereof as a dispersed phase forming component and the balance being tungsten carbide as a dispersed phase forming component and inevitable impurities.
 - 8. A coated cemented carbide endmill according to Claim 1 to 4, wherein said cemented carbide substrate have a composition of 5 - 20 wt% of Co as a binder phase forming component, 0.1 - 2 wt% of Cr and/or V as a binder phase forming component, 0.1 - 5 wt% of one or more kinds of carbides and nitrides of Ti, Ta, Nb and Zr as well as two or more kinds of solid solutions thereof as a dispersed phase forming component and the balance being tungsten carbide as a dispersed phase forming component and inevitable impurities.

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